Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 7.4 millimeters and 9.1 millimeters
Overall Diameter:
Between 5.5 millimeters and 6.0 millimeters
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
116.0 reverse breakdown voltage, dc and 94.0 working peak reverse voltage
Current Rating Per Characteristic:
5.00 microamperes forward current, average peak
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/507 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:

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